

HiPerFRED

V_{RRM} = 600 V
 I_{FAV} = 30 A
 t_{rr} = 35 ns

High Performance Fast Recovery Diode

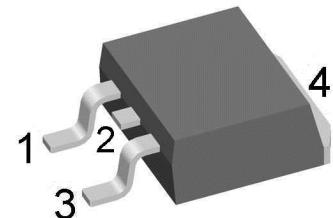
Low Loss and Soft Recovery

Single Diode

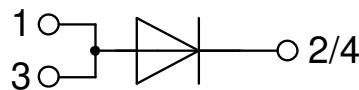
Part number

DSEP29-06AS

Marking on Product: DSEP29-06AS



Backside: cathode



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I_{rm} -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{rm} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: TO-263 (D2Pak)

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

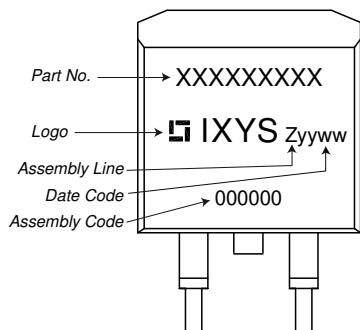
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Fast Diode

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
V_{RSM}	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			600	V
V_{RRM}	max. repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			600	V
I_R	reverse current, drain current	$V_R = 600 \text{ V}$ $V_R = 600 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 150^\circ\text{C}$		250 1	μA mA
V_F	forward voltage drop	$I_F = 30 \text{ A}$	$T_{VJ} = 25^\circ\text{C}$		1.61	V
		$I_F = 60 \text{ A}$			1.94	V
		$I_F = 30 \text{ A}$	$T_{VJ} = 150^\circ\text{C}$		1.26	V
		$I_F = 60 \text{ A}$			1.56	V
I_{FAV}	average forward current	$T_C = 135^\circ\text{C}$ rectangular	$T_{VJ} = 175^\circ\text{C}$		30	A
T_{VJ}		$d = 0.5$				
V_{F0}	threshold voltage		$T_{VJ} = 175^\circ\text{C}$		0.91	V
r_F	slope resistance } for power loss calculation only				9.4	$\text{m}\Omega$
R_{thJC}	thermal resistance junction to case				0.9	K/W
R_{thCH}	thermal resistance case to heatsink			0.25		K/W
P_{tot}	total power dissipation		$T_C = 25^\circ\text{C}$		165	W
I_{FSM}	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}; V_R = 0 \text{ V}$	$T_{VJ} = 45^\circ\text{C}$		250	A
C_J	junction capacitance	$V_R = 400 \text{ V}$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$		26	pF
I_{RM}	max. reverse recovery current		$T_{VJ} = 25^\circ\text{C}$		6	A
t_{rr}	reverse recovery time	$I_F = 30 \text{ A}; V_R = 300 \text{ V}$ $-di_F/dt = 200 \text{ A}/\mu\text{s}$	$T_{VJ} = 100^\circ\text{C}$		10	A
			$T_{VJ} = 25^\circ\text{C}$		35	ns
			$T_{VJ} = 100^\circ\text{C}$		100	ns

Package TO-263 (D2Pak)

Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			35	A
T_{VJ}	virtual junction temperature		-55		175	°C
T_{op}	operation temperature		-55		150	°C
T_{stg}	storage temperature		-55		150	°C
Weight				2		g
F_c	mounting force with clip		20		60	N

Product Marking


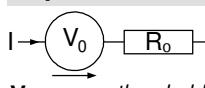
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSEP29-06AS-TRL	DSEP29-06AS	Tape & Reel	800	499498
Alternative	DSEP29-06AS-TUB	DSEP29-06AS	Tube	50	473537

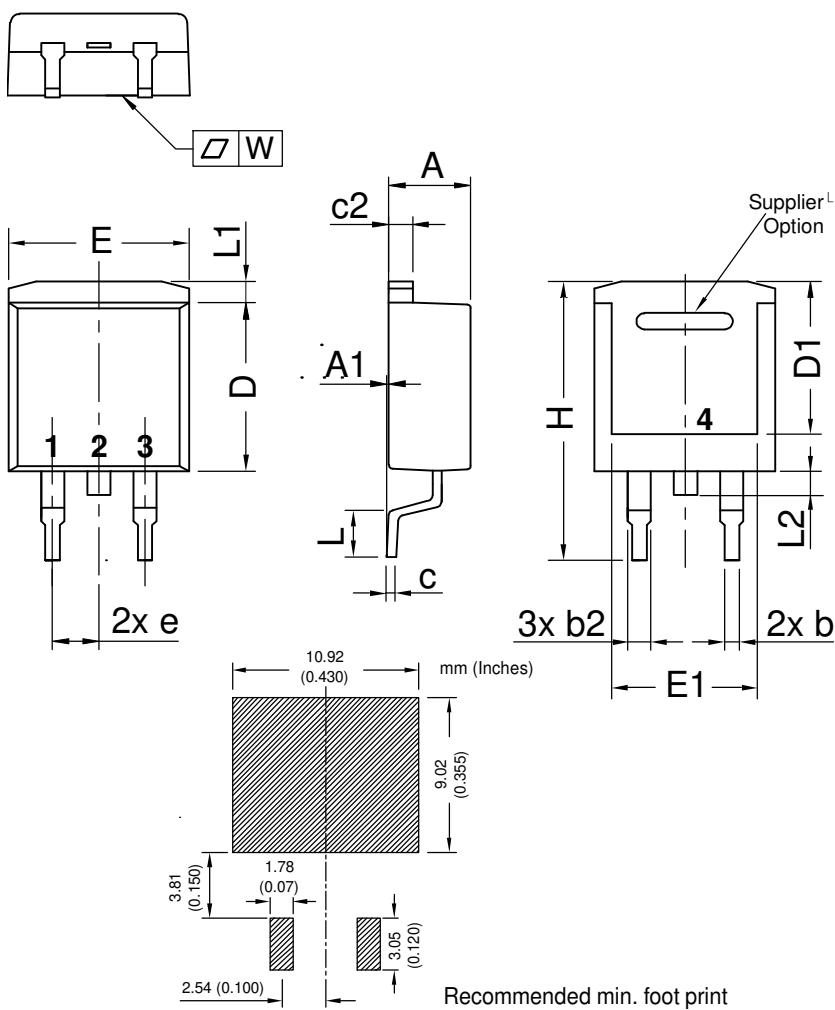
Similar Part	Package	Voltage class
DSEP29-06A	TO-220AC (2)	600
DSEP30-06A	TO-247AD (2)	600
DSEP30-06B	TO-247AD (2)	600
DSEP30-06BR	ISOPLUS247 (2)	600
DHG301600PA	TO-220AC (2)	600
DHG301600HA	TO-247AD (2)	600
DHG301M600PC	TO-263AB (D2Pak) (2)	600

Equivalent Circuits for Simulation

* on die level

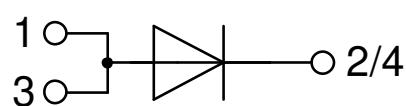
 $T_{VJ} = 175 \text{ }^{\circ}\text{C}$

	Fast Diode	
$V_{0\max}$	threshold voltage	0.91 V
$R_{0\max}$	slope resistance *	6.1 mΩ

Outlines TO-263 (D2Pak)


Dim.	Millimeter		Inches	
	min	max	min	max
A	4.06	4.83	0.160	0.190
A1	typ. 0.10		typ. 0.004	
A2	2.41		0.095	
b	0.51	0.99	0.020	0.039
b2	1.14	1.40	0.045	0.055
c	0.40	0.74	0.016	0.029
c2	1.14	1.40	0.045	0.055
D	8.38	9.40	0.330	0.370
D1	8.00	8.89	0.315	0.350
D2	2.5		0.098	
E	9.65	10.41	0.380	0.410
E1	6.22	8.50	0.245	0.335
e	2,54 BSC		0,100 BSC	
e1	4.28		0.169	
H	14.61	15.88	0.575	0.625
L	1.78	2.79	0.070	0.110
L1	1.02	1.68	0.040	0.066
W	typ. 0.02	0.040	typ. 0.0008	0.002

All dimensions conform with
and/or within JEDEC standard.



Fast Diode

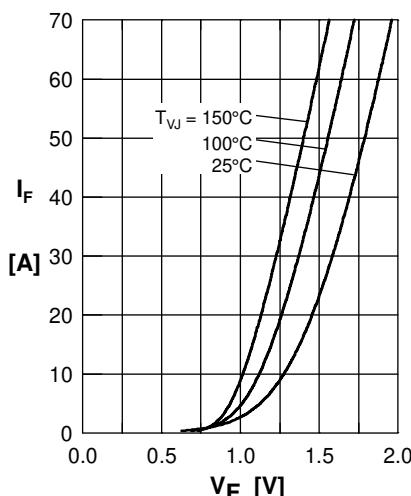


Fig. 1 Forward current I_F versus V_F

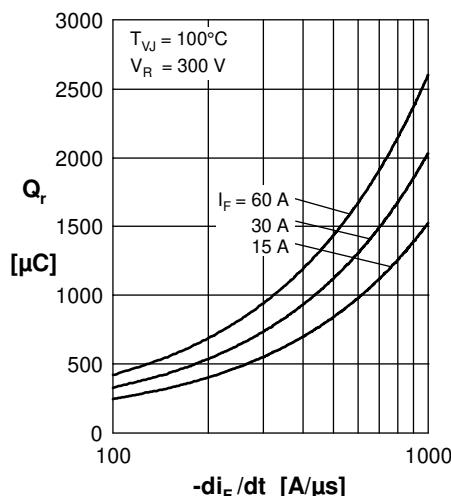


Fig. 2 Typ. reverse recov. charge Q_r versus $-di_F/dt$

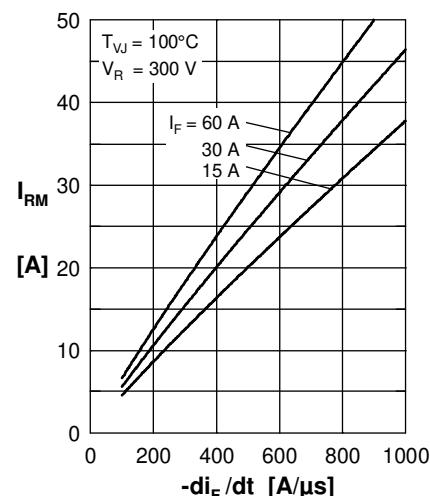


Fig. 3 Typ. peak reverse current I_{RM} versus $-di_F/dt$

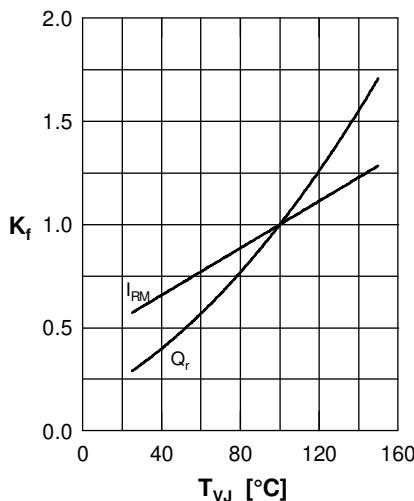


Fig. 4 Dynamic parameters Q_r , I_{RM} versus T_{VJ}

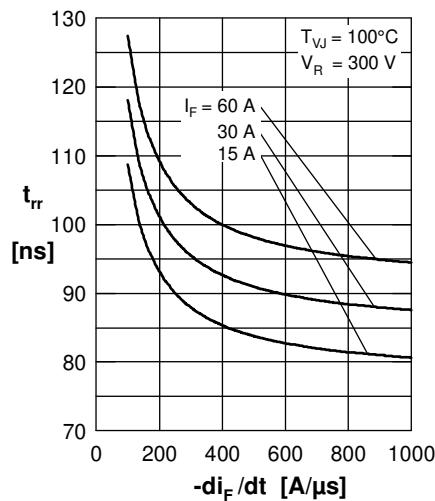


Fig. 5 Typ. recovery time t_{rr} versus $-di_F/dt$

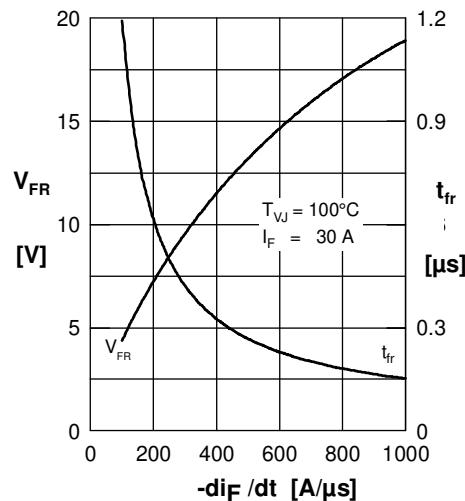
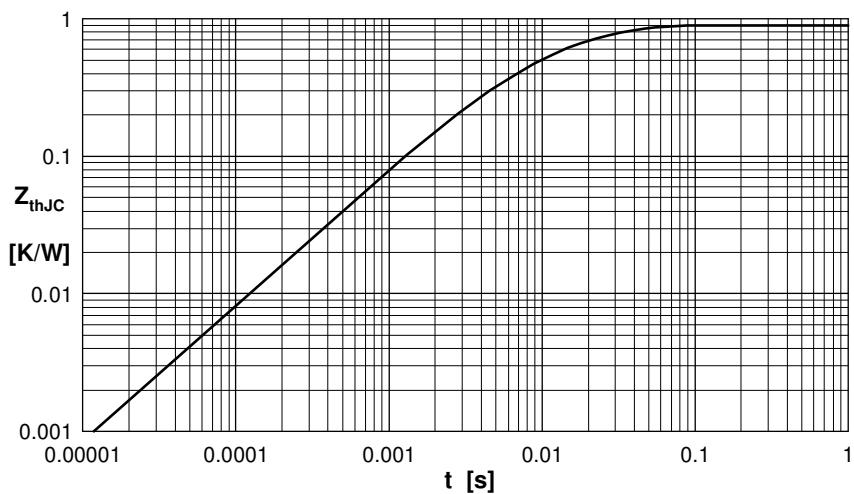


Fig. 6 Typ. peak forward voltage V_{FR} and t_{fr} versus di_F/dt



Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.030	0.001
2	0.080	0.030
3	0.300	0.006
4	0.490	0.060

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